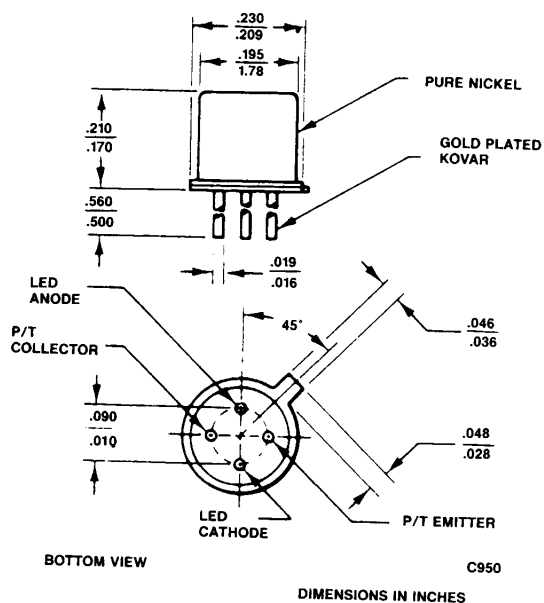


PACKAGE DIMENSIONS



DESCRIPTION

The MCT4R is a standard four-lead, TO-18 package containing a GaAs infrared emitting diode optically coupled to a silicon planar phototransistor.

FEATURES

- Hermetic package
- High current transfer ratio; typically 35%
- High isolation resistance, 10^{11} ohms at 500 volts
- High voltage isolation emitter to detector
- Screened to MIL-STD-883 Class B

APPLICATIONS

The MCT4R is designed and manufactured to conform to the requirements of military systems. Reliability testing has proven the product capable of conforming to the screening and quality conformance requirements of MIL-STD-883C Class B devices.

SCREEN—100%	
Characteristic	Method
Internal Visual	2010 — Characteristics applicable to device
Stabilization Bake	1008 — 150°C. for 48 hours
Temperature Cycle	1010 — 10 cycles; -55°C., 25°C., 150°C., 25°C.
Centrifuge	2001 — Test Condition E
Hermeticity	1014 — Fine and Gross
Critical Electrical	— Data Sheet
Burn In	1015 — 160 hours @ 125°C
Final Electrical	— Data Sheet
Group A Sample Inspection	5005 Table I Subgroups
External Visual	2009



RELIABILITY CONDITIONED HERMETIC PHOTOTRANSISTOR OPTOCOUPLER

LOT QUALIFICATION TESTS		
CHARACTERISTIC	METHOD	LTPD
Subgroup I Visual Mechanical Marking Permanency Physical Dimensions	2008	15%
Subgroup II Solderability	2003	15%
Subgroup III Thermal Shock Temperature Cycle Moisture Resistance Critical Electrical	1011 — 15 cycles; 150°C. to -65°C. 1010 — 10 cycles; -55°C., 25°C., 150°C., 25°C. 1004 — Data Sheet	15%
Subgroup IV Mechanical Shock Vibration Fatigue Vibration Variable Frequency Constant Acceleration Critical Electrical	2002 — Condition B 2005 — Condition A 2007 — Condition A 2001 — Condition E — Data Sheets	15%
Subgroup V Lead Fatigue Hermeticity	2004 — Condition B ₂ 1014 — Fine Condition A Gross Condition C	15%
Subgroup VI Salt Atmosphere	1009 — Condition A	15%

LIFE TESTING 7% LTPD		
CHARACTERISTIC	METHOD	LTPD
Subgroup VII High Temperature Storage Critical Electrical	1008 — 150°C. for 1000 hours — Data Sheet	7%
Subgroup VIII Operating Life Critical Electrical	1005 — Condition B — Data Sheets	7%
Subgroup IX Steady State Reverse Bias	1015 — Condition A; 72 hours at 150°C.	7%
Subgroup X Bond Strength	2001 — Condition C; 10 devices only	

Reference: MIL-STD-883C Test Methods and Procedures for Microelectronics.



RELIABILITY CONDITIONED HERMETIC PHOTOTRANSISTOR OPTOCOUPLER

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.